

MBRF1035CT - MBRF10200CT

Isolated 10.0 AMPS. Schottky Barrier Rectifiers

ITO-220AB

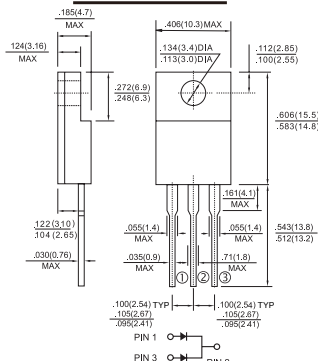


Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guarding for overvoltage protection
- High temperature soldering guaranteed:
260°C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

- Cases: ITO-220AB molded plastic
- Terminals: Pure tin plated, lead free, solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. - lbs. max
- Weight: 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)



Marking Diagram

MBRF10XXCT = Specific Device Code

Y = Year
WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 1035 CT	MBRF 1045 CT	MBRF 1050 CT	MBRF 1060 CT	MBRF 1090 CT	MBRF 10100 CT	MBRF 10150 CT	MBRF 10200 CT	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	35	45	50	60	90	100	150	200	V
Maximum RMS Voltage	V _{RMS}	24	31	35	42	63	70	105	140	V
Maximum DC Blocking Voltage	V _{DC}	35	45	50	60	90	100	150	200	V
Maximum Average Forward Rectified Current at T _C =133°C	I _(AV)	10								A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at T _C =133°C	I _{FRM}	10								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	120								A
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	0.5								A
Maximum Instantaneous Forward Voltage at (Note 2) I _F = 5A, T _C =25°C I _F = 5A, T _C =125°C I _F =10A, T _C =25°C I _F =10A, T _C =125°C	V _F	0.70 0.57 0.80 0.67	0.80 0.65 0.90 0.75		0.85 0.75 0.95 0.85		0.88 0.78 0.98 0.88		V	
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @T _C =25 °C @ T _C =125 °C	I _R	0.1 15 10 5.0								mA mA
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000								V/μS
RMS Isolation Voltage (t=1.0 second, R.H. ≤30%, T _A =25°C) (Note 4) (Note 5) (Note 6)	V _{ISO}	4500 3500 1500								V
Typical Thermal Resistance Per Leg (Note3)	RθJC	3.5								°C/W
Operating Junction Temperature Range	T _J	-65 to +150								°C
Storage Temperature Range	T _{STG}	-65 to +150								°C

- Notes:
- 2.0 μs Pulse Width, $f=1.0$ KHz
 - Pulse Test: 300 μs Pulse Width, 1% Duty Cycle
 - Thermal Resistance from Junction to Case Per Leg.
 - Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.
 - Clip mounting (on case), where leads do overlap heatsink.
 - Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")

RATINGS AND CHARACTERISTIC CURVES (MBRF1035CT THRU MBRF10200CT)

FIG.1- FORWARD CURRENT DERATING CURVE

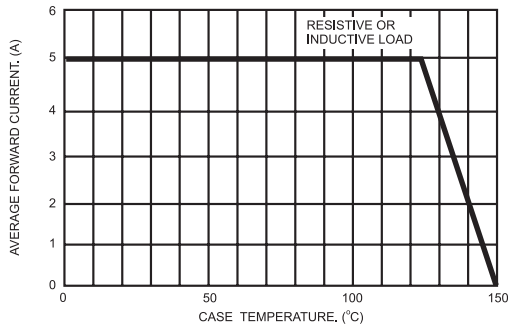


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

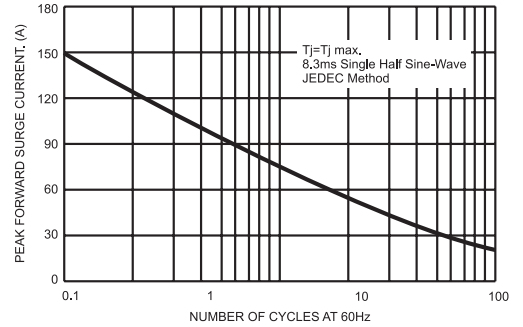


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

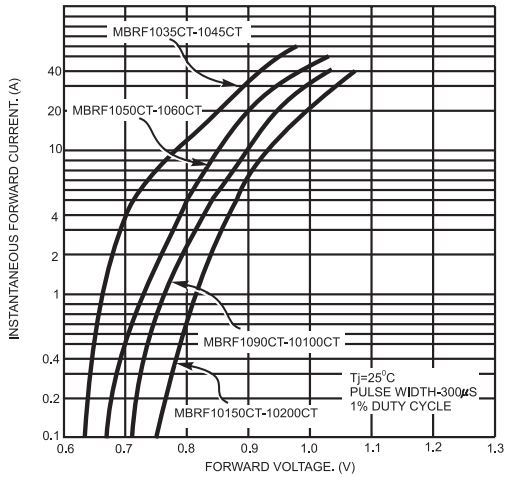


FIG.4- TYPICAL REVERSE CHARACTERISTICS

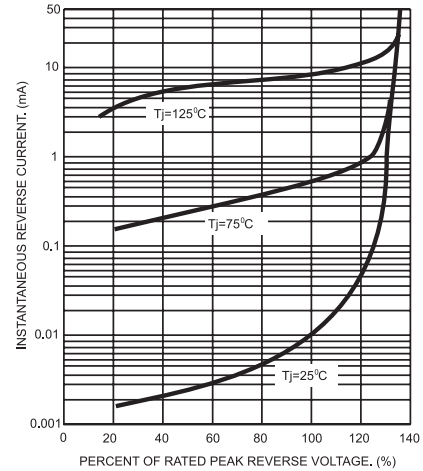


FIG.5- TYPICAL JUNCTION CAPACITANCE

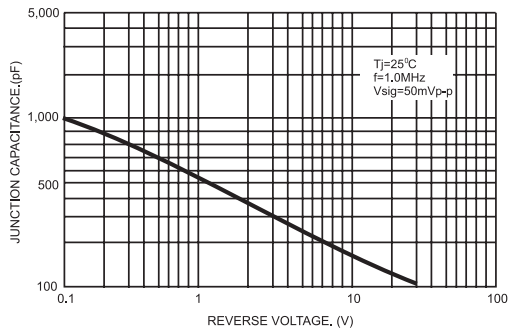


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS PER LEG

